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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	200MHz
Connectivity	CSIO, EBI/EMI, Ethernet, I ² C, LINbus, SD, SPI, UART/USART, USB
Peripherals	DMA, I ² S, LVD, POR, PWM, WDT
Number of I/O	152
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	256K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 32x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	192-LFBGA
Supplier Device Package	192-FBGA (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/s6e2c2aj0agb1000a

Multi-function Serial Interface (Max 16 channels)

- Separate 64 byte receive and transmit FIFO buffers for channels 0 to 7.
- Operation mode is selectable for each channel from the following:
 - UART
 - CSIO (SPI)
 - LIN
 - I²C
- UART
 - Full-duplex double buffer
 - Selection with or without parity supported
 - Built-in dedicated baud rate generator
 - External clock available as a serial clock
 - Various error detect functions available (parity errors, framing errors, and overrun errors)
- CSIO (SPI)
 - Full-duplex double buffer
 - Built-in dedicated baud rate generator
 - Overrun error detect function available
 - Serial chip select function (ch 6 and ch 7 only)
 - Supports high-speed SPI (ch 4 and ch 6 only)
 - Data length 5 to 16-bit
- LIN
 - LIN protocol Rev.2.1 supported
 - Full-duplex double buffer
 - Master/slave mode supported
 - LIN break field generation (can change to 13- to 16-bit length)
 - LIN break delimiter generation (can change to 1- to 4-bit length)
 - Various error detect functions available (parity errors, framing errors, and overrun errors)
- I²C
 - Standard mode (Max 100 kbps)/Fast mode (Max 400 kbps) supported
 - Fast mode Plus (Fm+) (Max 1000 kbps, only for ch 3 = ch A and ch 7 = ch B) supported

DMA Controller (Eight channels)

DMA controller has an independent bus, so the CPU and DMA controller can process simultaneously.

- Eight independently configured and operated channels
- Transfer can be started by software or request from the built-in peripherals
- Transfer address area: 32-bit (4 GB)
- Transfer mode: Block transfer/Burst transfer/Demand transfer
- Transfer data type: bytes/half-word/word
- Transfer block count: 1 to 16
- Number of transfers: 1 to 65536

DSTC (Descriptor System data Transfer Controller; 256 Channels)

The DSTC can transfer data at high-speed without going via the CPU. The DSTC adopts the descriptor system and, following the specified contents of the descriptor that has already been constructed on the memory, can access directly the memory/peripheral device and perform the data-transfer operation.

It supports the software activation, the hardware activation, and the chain activation functions.

A/D Converter (Max 32 channels)

- 12-bit A/D Converter
 - Successive approximation type
 - Built-in three units
 - Conversion time: 0.5 μ s at 5 V
 - Priority conversion available (priority at two levels)
 - Scanning conversion mode
 - Built-in FIFO for conversion data storage (for SCAN conversion: 16 steps, for priority conversion: 4 steps)

D/A Converter (Max 2 Channels)

- R-2R type
- 12-bit resolution

Base Timer (Max 16 Channels)

Operation mode is selected from the following for each channel:

- 16-bit PWM timer
- 16-bit PPG timer
- 16-/32-bit reload timer
- 16-/32-bit PWC timer

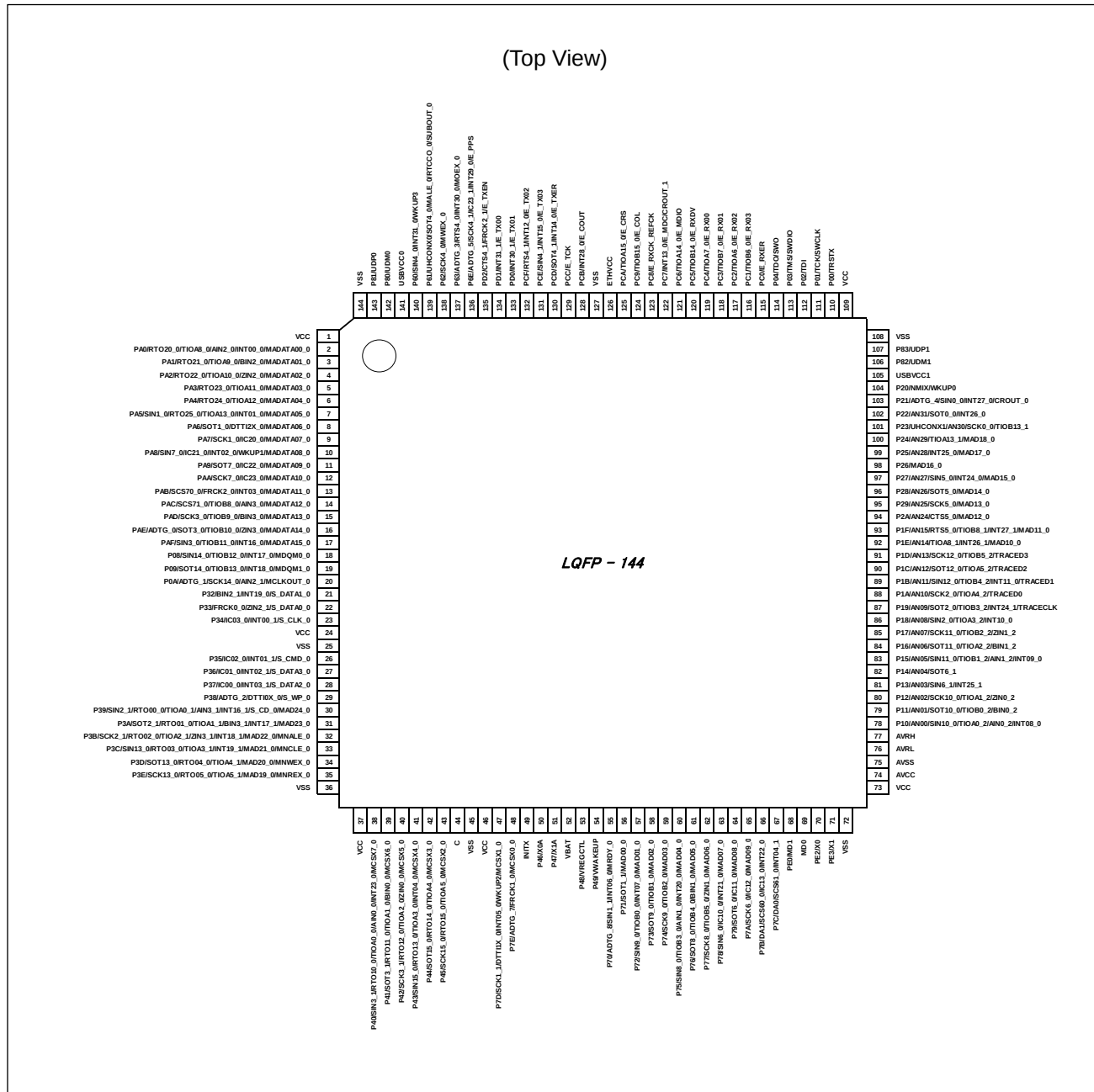
General Purpose I/O Port

This series can use its pins as general purpose I/O ports when they are not used for external bus or peripherals; moreover, the port relocate function is built in. It can set the I/O port to which the peripheral function can be allocated.

- Capable of pull-up control per pin
- Capable of reading pin level directly
- Built-in port-relocate function
- Up to 120 high-speed general-purpose I/O ports in 144 pin package
- Some pins 5V tolerant I/O.
See 4. Pin Descriptions and 5. I/O Circuit Type for the corresponding pins.

3. Pin Assignments

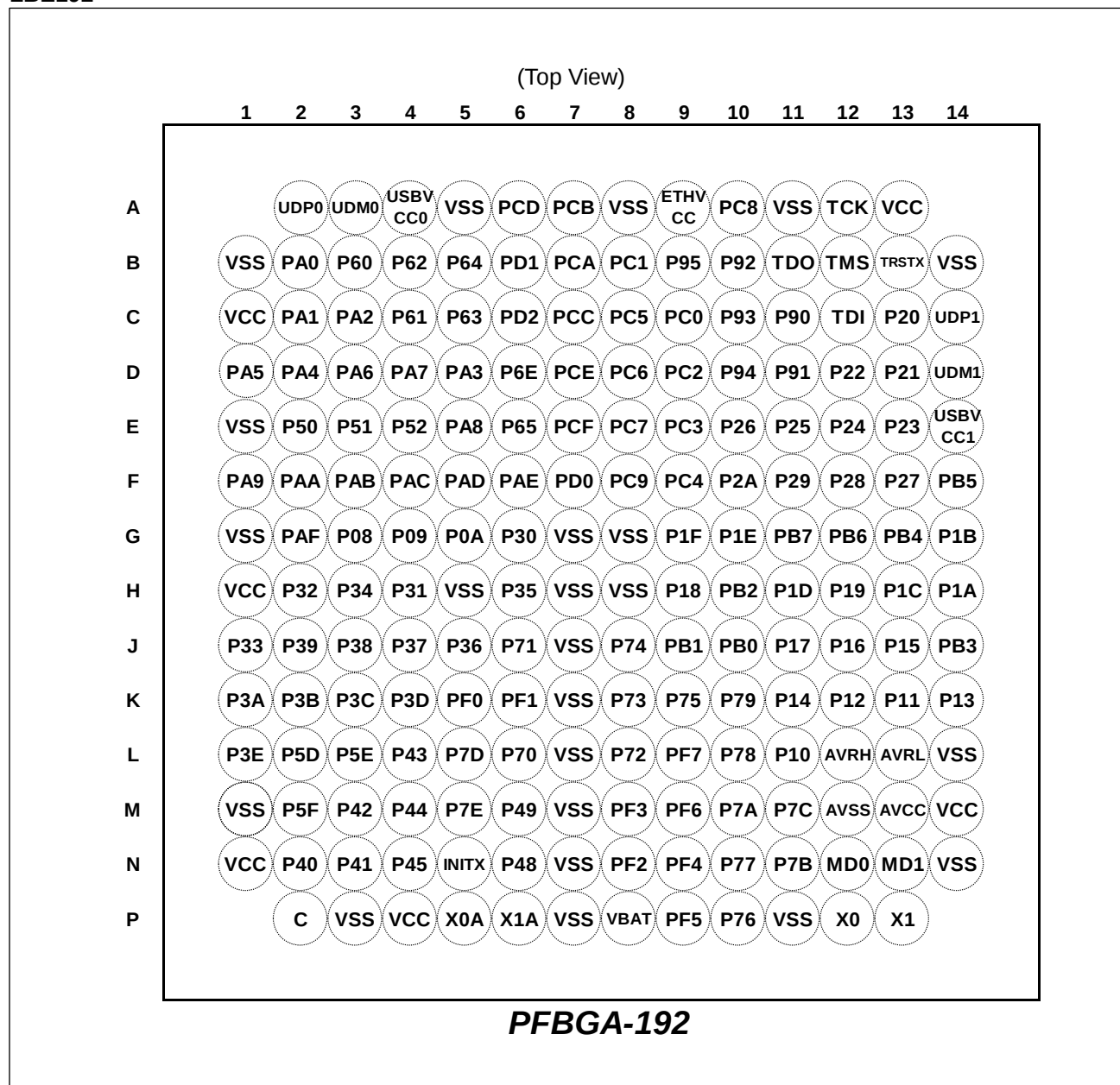
LQS144



Note:

- The number after the underscore ("_") in pin names such as XXX_1 and XXX_2 indicates the relocated port number. For these pins, there are multiple pins that provide the same function for the same channel. Use the extended port function register (EPFR) to select the pin.

LBE192



Note:

- The number after the underscore ("_") in pin names such as XXX_1 and XXX_2 indicates the relocated port number. For these pins, there are multiple pins that provide the same function for the same channel. Use the extended port function register (EPFR) to select the pin.

Signal Descriptions

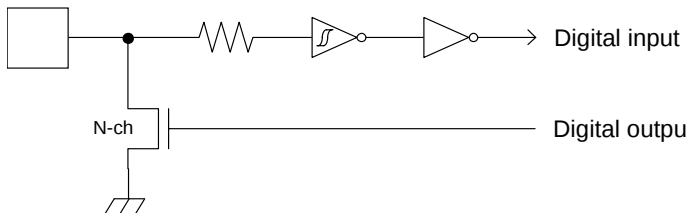
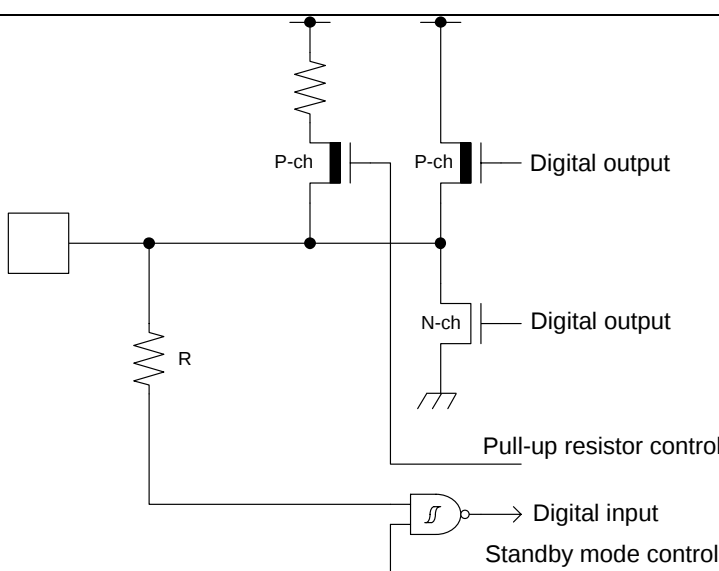
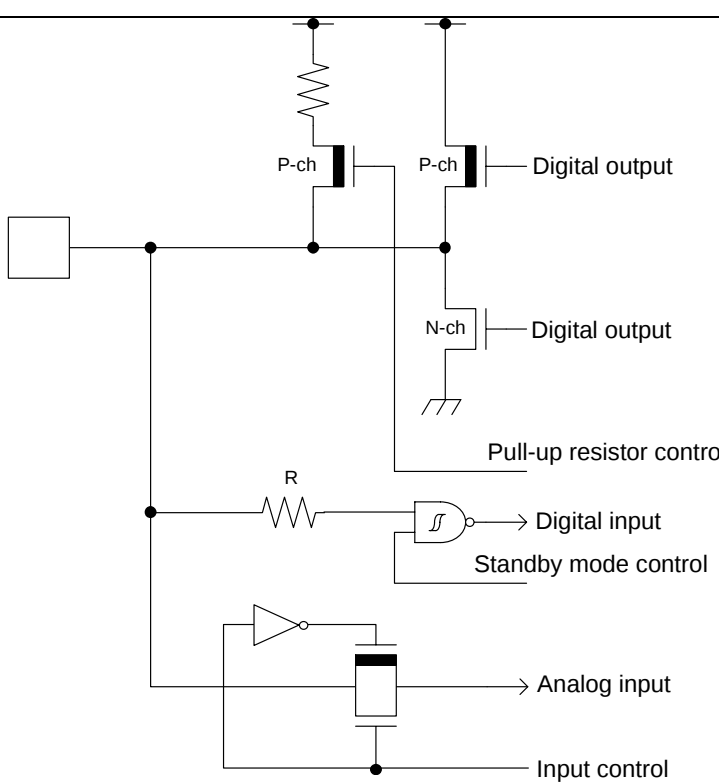
The number after the underscore ("_") in pin names such as XXX_1 and XXX_2 indicates the relocated port number. For these pins, there are multiple pins that provide the same function for the same channel.

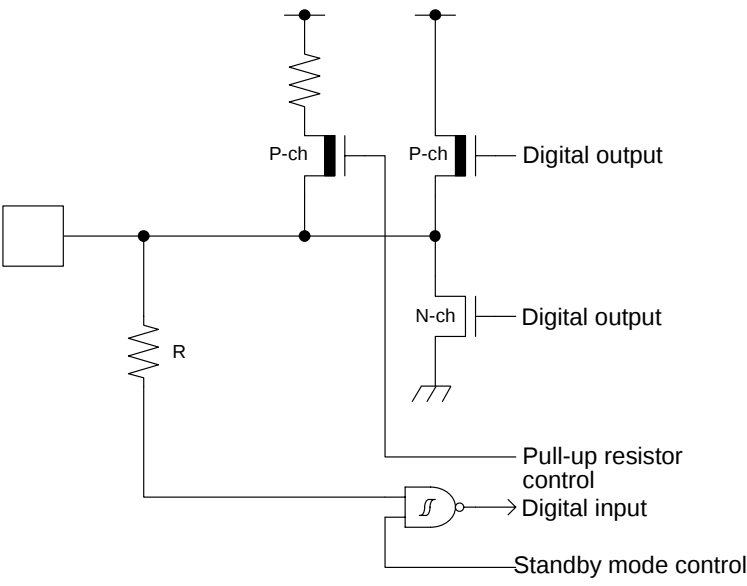
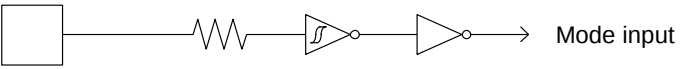
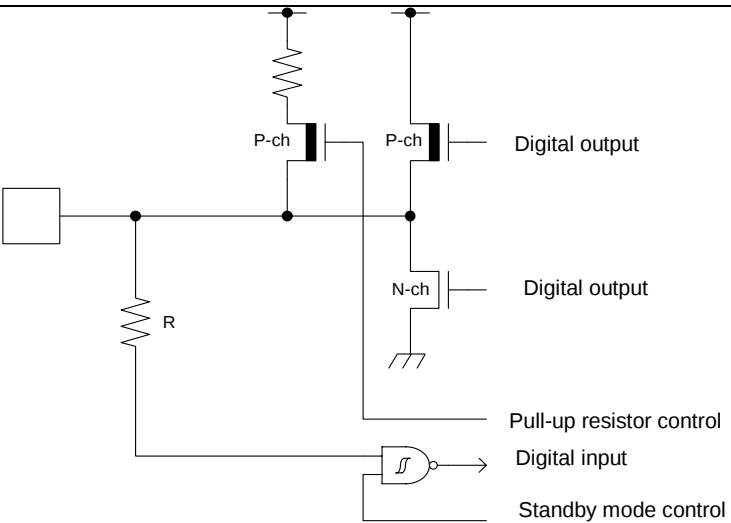
Use the extended port function register (EPFR) to select the pin.

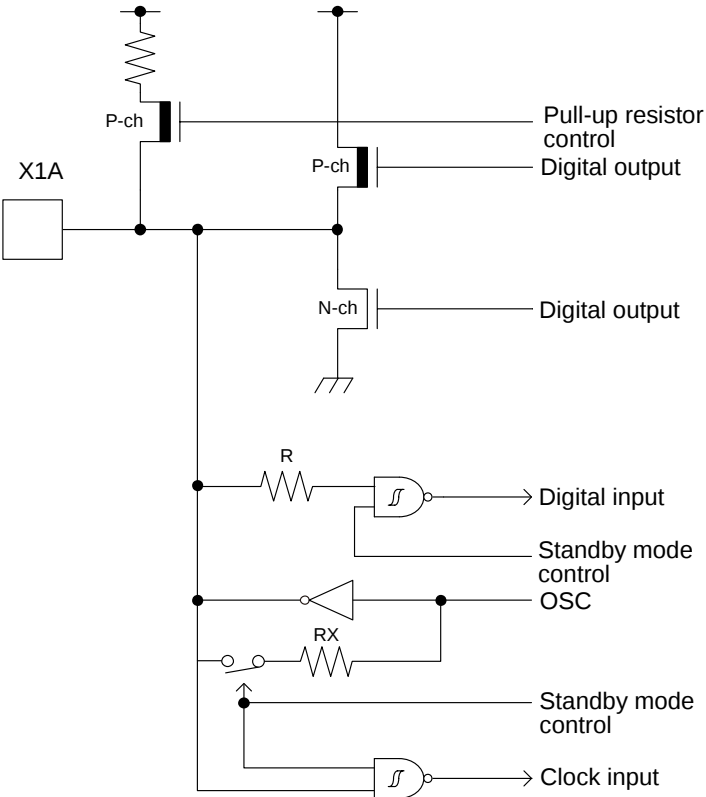
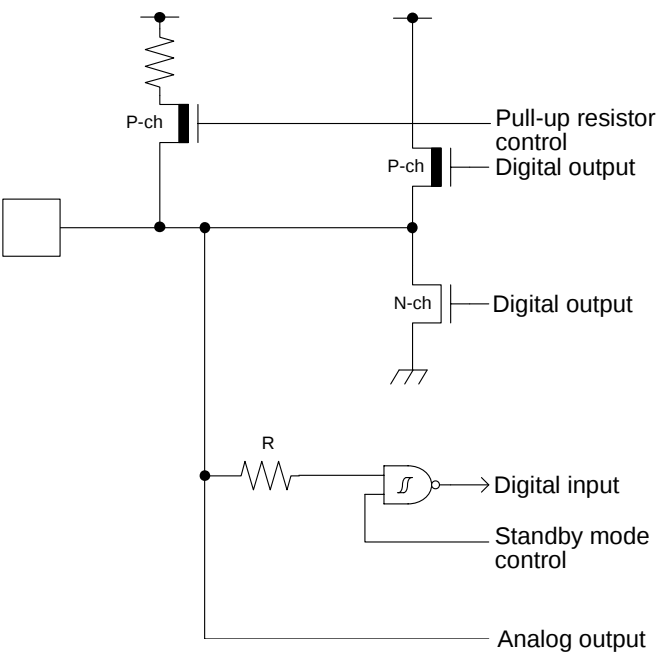
Module	Pin Name	Function	Pin Number			
			LQQ 216	LQP 176	LQS 144	LBE 192
A/D converter	ADTG_0	A/D converter external trigger input pin	24	19	16	F6
	ADTG_1		32	23	20	G5
	ADTG_2		44	34	29	J3
	ADTG_3		209	169	137	C5
	ADTG_4		157	127	103	D13
	ADTG_5		198	166	136	D6
	ADTG_6		119	-	-	-
	ADTG_7		71	56	48	M5
	ADTG_8		80	65	55	L6
	AN00	A/D converter analog input pin. ANxx describes A/D converter ch xx.	114	94	78	L11
	AN01		115	95	79	K13
	AN02		116	96	80	K12
	AN03		117	97	81	K14
	AN04		118	98	82	K11
	AN05		123	99	83	J13
	AN06		124	100	84	J12
	AN07		125	101	85	J11
	AN08		130	106	86	H9
	AN09		131	107	87	H12
	AN10		132	108	88	H14
	AN11		133	109	89	G14
	AN12		134	110	90	H13
	AN13		135	111	91	H11
	AN14		142	116	92	G10
	AN15		143	117	93	G9
	AN16		126	102	-	J10
	AN17		127	103	-	J9
	AN18		128	104	-	H10
	AN19		129	105	-	J14
	AN20		138	112	-	G13
	AN21		139	113	-	F14
	AN22		140	114	-	G12
	AN23		141	115	-	G11
	AN24		144	118	94	F10
	AN25		145	119	95	F11
	AN26		146	120	96	F12
	AN27		147	121	97	F13
	AN28		153	123	99	E11
	AN29		154	124	100	E12
	AN30		155	125	101	E13
	AN31		156	126	102	D12

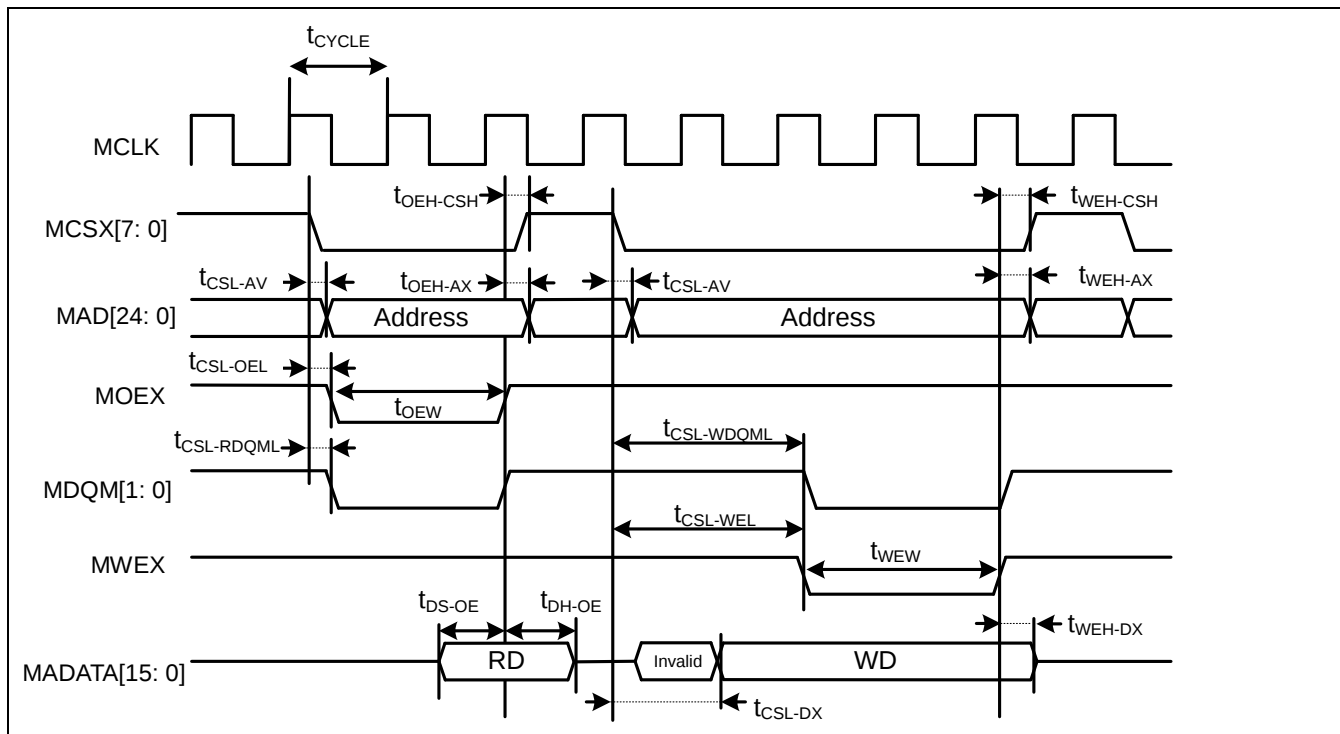
Module	Pin Name	Function	Pin Number			
			LQQ 216	LQP 176	LQS 144	LBE 192
Debugger	SWCLK	Serial wire debug interface clock input pin	165	135	111	A12
	SWDIO	Serial wire debug interface data input/output pin	167	137	113	B12
	SWO	Serial wire viewer output pin	168	138	114	B11
	TCK	JTAG test clock input pin	165	135	111	A12
	TDI	JTAG test data input pin	166	136	112	C12
	TDO	JTAG debug data output pin	168	138	114	B11
	TMS	JTAG test mode state input/output pin	167	137	113	B12
	TRACECLK	Trace CLK output pin of ETM/HTM	131	107	87	H12
	TRACED0	Trace data output pin of ETM/ Trace data output pin of HTM	132	108	88	H14
	TRACED1		133	109	89	G14
	TRACED2		134	110	90	H13
	TRACED3		135	111	91	H11
	TRACED4	Trace data output pin of HTM	138	112	-	G13
	TRACED5		139	113	-	F14
	TRACED6		140	114	-	G12
	TRACED7		141	115	-	G11
	TRACED8		119	-	-	-
	TRACED9		120	-	-	-
	TRACED10		121	-	-	-
	TRACED11		122	-	-	-
	TRACED12		148	-	-	-
	TRACED13		149	-	-	-
	TRACED14		150	-	-	-
	TRACED15		151	-	-	-
	TRSTX	JTAG test reset Input pin	164	134	110	B13

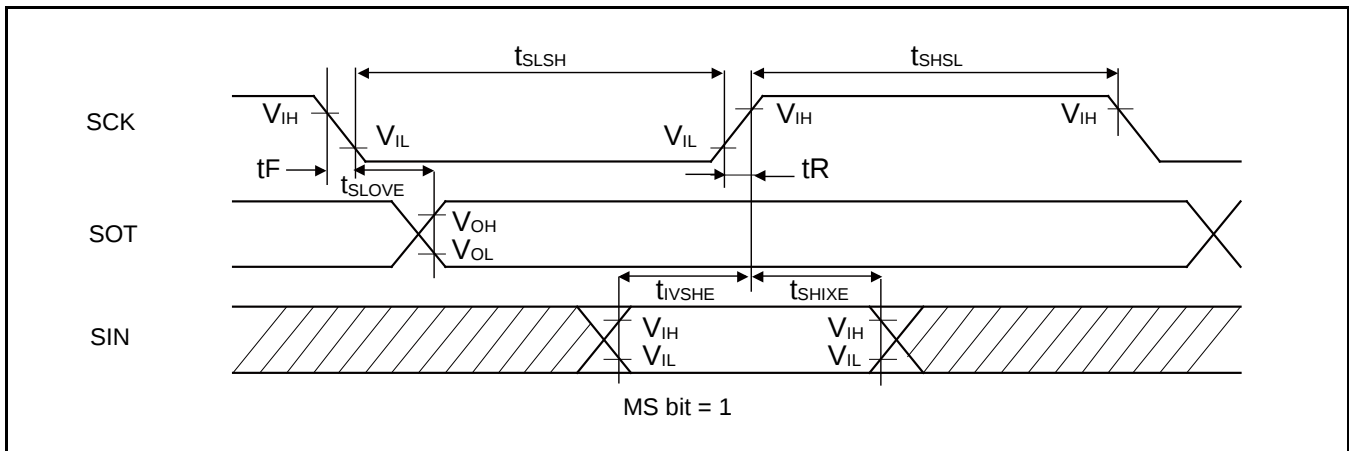
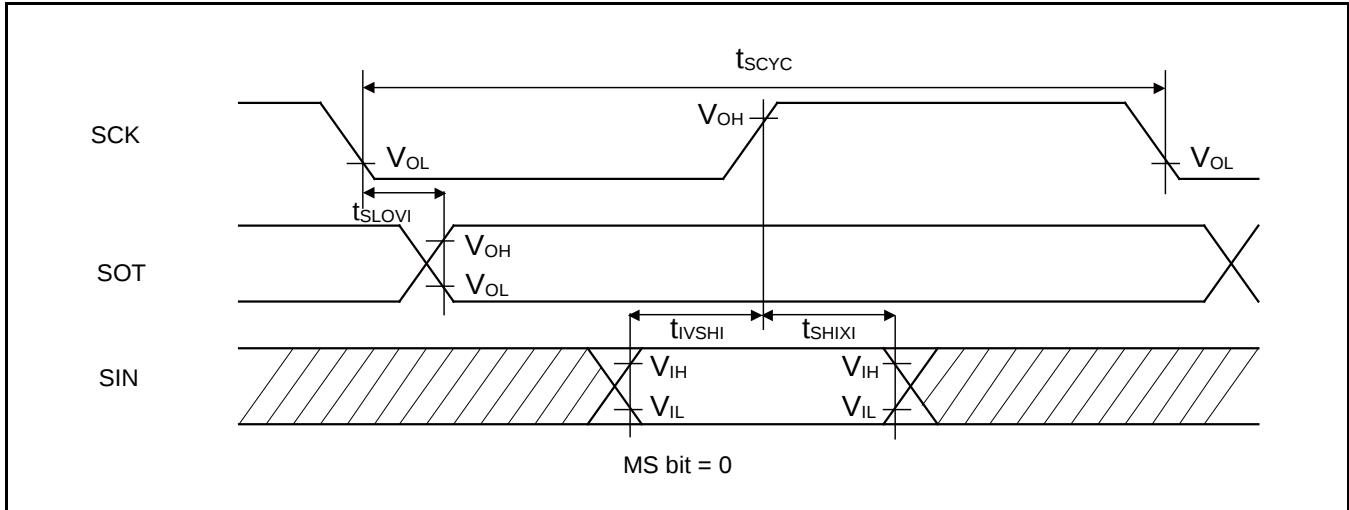
Module	Pin Name	Function	Pin Number			
			LQQ 216	LQP 176	LQS 144	LBE 192
External bus	MADATA00_0	External bus interface data bus (address/data multiplex bus)	2	2	2	B2
	MADATA01_0		3	3	3	C2
	MADATA02_0		4	4	4	C3
	MADATA03_0		5	5	5	D5
	MADATA04_0		6	6	6	D2
	MADATA05_0		7	7	7	D1
	MADATA06_0		8	8	8	D3
	MADATA07_0		9	9	9	D4
	MADATA08_0		14	13	10	E5
	MADATA09_0		15	14	11	F1
	MADATA10_0		16	15	12	F2
	MADATA11_0		17	16	13	F3
	MADATA12_0		18	17	14	F4
	MADATA13_0		23	18	15	F5
	MADATA14_0		24	19	16	F6
	MADATA15_0		25	20	17	G2
	MADATA16_0		10	-	-	-
	MADATA17_0		11	-	-	-
	MADATA18_0		12	-	-	-
	MADATA19_0		13	-	-	-
	MADATA20_0		19	-	-	-
	MADATA21_0		20	-	-	-
	MADATA22_0		21	-	-	-
	MADATA23_0		22	-	-	-
	MADATA24_0		26	-	-	-
	MADATA25_0		27	-	-	-
	MADATA26_0		28	-	-	-
	MADATA27_0		29	-	-	-
	MADATA28_0		33	-	-	-
	MADATA29_0		51	-	-	-
	MADATA30_0		52	-	-	-
	MADATA31_0		53	-	-	-
	MDQM0_0	External bus interface byte mask signal output pin	30	21	18	G3
	MDQM1_0		31	22	19	G4
	MDQM2_0		34	-	-	-
	MDQM3_0		35	-	-	-
	MALE_0	External bus interface address latch enable output signal for multiplex	211	171	139	C4
	MRDY_0	External bus interface external RDY input signal	80	65	55	L6

Type	Circuit	Remarks
C		• Open drain output • CMOS level hysteresis input
E		• CMOS level output • CMOS level hysteresis input • Pull-up resistor control • Standby mode control • Pull-up resistor: approximately 50 kΩ • $I_{OH} = -4 \text{ mA}$, $I_{OL} = 4 \text{ mA}$ • When this pin is used as an I²C pin, the digital output P-ch transistor is always off.
F		• CMOS level output • CMOS level hysteresis input • Input control • Analog input • Pull-up resistor control • Standby mode control • Pull-up resistor: approximately 50 kΩ • $I_{OH} = -4 \text{ mA}$, $I_{OL} = 4 \text{ mA}$ • When this pin is used as an I²C pin, the digital output P-ch transistor is always off.

Type	Circuit	Remarks
I		• CMOS level output • CMOS level hysteresis input • 5V tolerant • Pull-up resistor control • Standby mode control • Pull-up resistor: approximately 50 kΩ • $I_{OH} = -4 \text{ mA}$, $I_{OL} = 4 \text{ mA}$ • Available to control of PZR registers (pseudo-open drain control) • For PZR registers, refer to GPIO in the “FM4 Family Peripheral Manual Main Part (002-04856)”.
J		CMOS level hysteresis input
K		• CMOS level output • TTL level hysteresis input • Pull-up resistor control • Standby mode control • Pull-up resistor: approximately 50 kΩ • $I_{OH} = -4 \text{ mA}$, $I_{OL} = 4 \text{ mA}$

Type	Circuit	Remarks
Q	 Pull-up resistor control Digital output Digital output Digital input Standby mode control OSC Standby mode control Clock input	It is possible to select the sub oscillation/GPIO function. When the sub oscillation is selected: - Oscillation feedback resistor: approximately 10 MΩ When the GPIO is selected: - CMOS level output. - CMOS level hysteresis input - Pull-up resistor control - Pull-up resistor: approximately 50 kΩ $I_{OH} = -4 \text{ mA}$, $I_{OL} = 4 \text{ mA}$ - For I/O setting, refer to VBAT Domain in the "FM4 Family Peripheral Manual Main Part (002-04856)."
R	 Pull-up resistor control Digital output Digital output Digital input Standby mode control Analog output	- CMOS level output - CMOS level hysteresis input - Analog output - Pull-up resistor control - Standby mode control - Pull-up resistor: approximately 50 kΩ $I_{OH} = -4 \text{ mA}$, $I_{OL} = 4 \text{ mA}$ (4.5V to 5.5V) $I_{OH} = -2 \text{ mA}$, $I_{OL} = 2 \text{ mA}$ (2.7V to 4.5V)





When Using Synchronous Serial Chip Select (SCINV = 0, CSLVL = 0)

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Conditions	V _{CC} < 4.5 V		V _{CC} ≥ 4.5 V		Unit
			Min	Max	Min	Max	
SCS↑→SCK↓ setup time	t _{CSSI}	Internal shift clock operation	(*1)-50	(*1)+0	(*1)-50	(*1)+0	ns
SCK↑→SCS↓ hold time	t _{CSHI}		(*2)+0	(*2)+50	(*2)+0	(*2)+50	ns
SCS deselect time	t _{CSDI}		(*3)-50 +5t _{CYCP}	(*3)+50 +5t _{CYCP}	(*3)-50 +5t _{CYCP}	(*3)+50 +5t _{CYCP}	ns
SCS↑→SCK↓ setup time	t _{CSSE}	External shift clock operation	3t _{CYCP} +30	-	3t _{CYCP} +30	-	ns
SCK↑→SCS↓ hold time	t _{CSHE}		0	-	0	-	ns
SCS deselect time	t _{CSDE}		3t _{CYCP} +30	-	3t _{CYCP} +30	-	ns
SCS↑→SOT delay time	t _{DSE}		-	40	-	40	ns
SCS↓→SOT delay time	t _{DEE}		0	-	0	-	ns

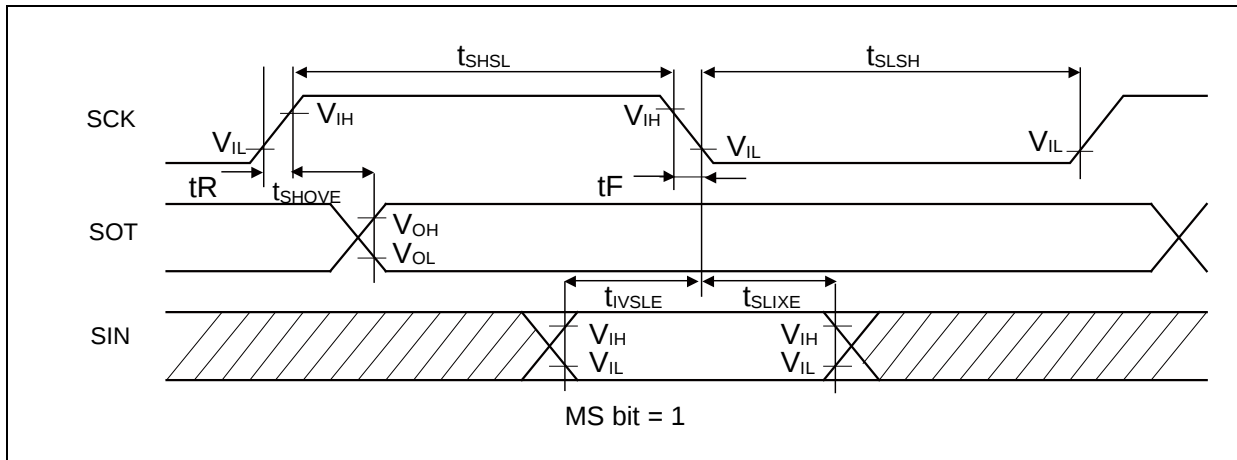
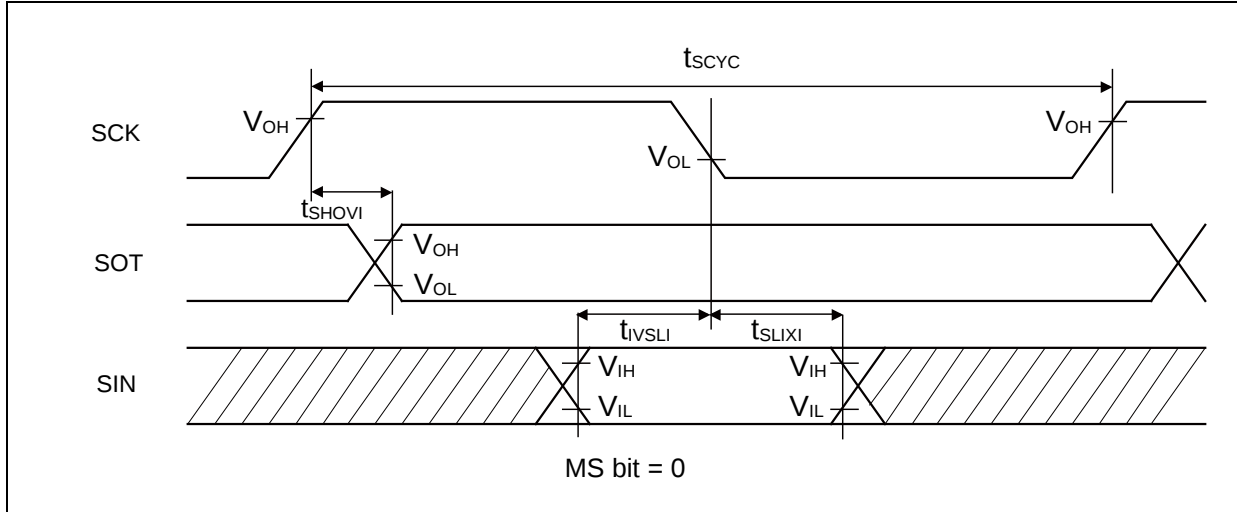
(*1): CSSU bit value×serial chip select timing operating clock cycle [ns]

(*2): CSHD bit value×serial chip select timing operating clock cycle [ns]

(*3): CSDS bit value×serial chip select timing operating clock cycle [ns]

Notes:

- t_{CYCP} indicates the APB bus clock cycle time. For more information about the APB bus number to which the multi-function serial is connected, see 8. Block Diagram in this data sheet.
- For more information about CSSU, CSHD, CSDS, and the serial chip select timing operating clock, see FM4 Family Peripheral Manual Main Part (002-04856).
- When the external load capacitance C_L = 30 pF.



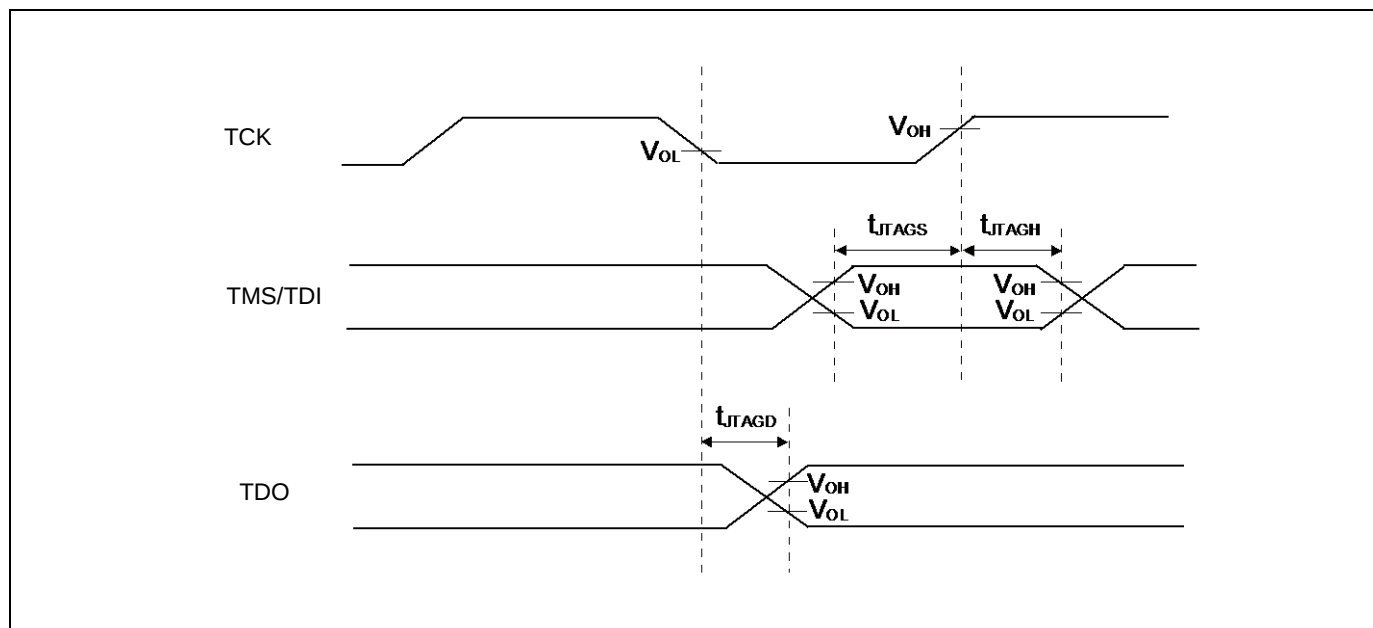
12.4.18 JTAG Timing

($V_{CC} = 2.7V$ to $5.5V$, $V_{SS} = 0V$)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
TMS, TDI setup time	t_{JTAGS}	TCK, TMS, TDI	$V_{CC} \geq 4.5 V$ $V_{CC} < 4.5 V$	15	-	ns	
TMS, TDI hold time	t_{JTAGH}	TCK, TMS, TDI	$V_{CC} \geq 4.5 V$ $V_{CC} < 4.5 V$	15	-	ns	
TDO delay time	t_{JTAGD}	TCK, TDO	$V_{CC} \geq 4.5 V$	-	25	ns	
			$V_{CC} < 4.5 V$	-	45		

Note:

- When the external load capacitance $C_L = 30 pF$.



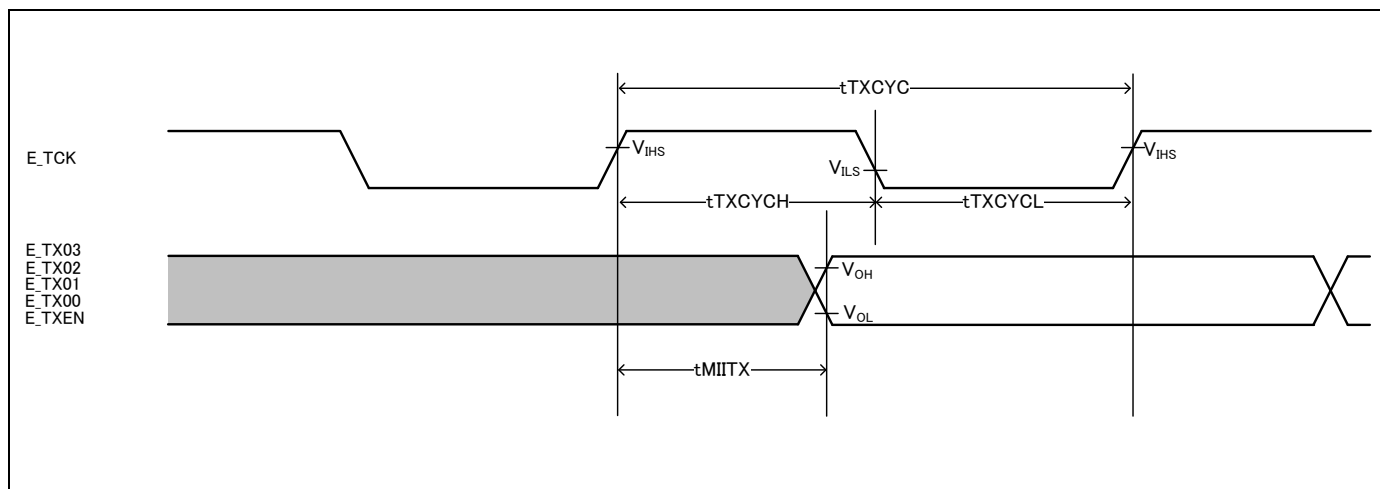
MII Transmission (100 Mbps/10 Mbps)

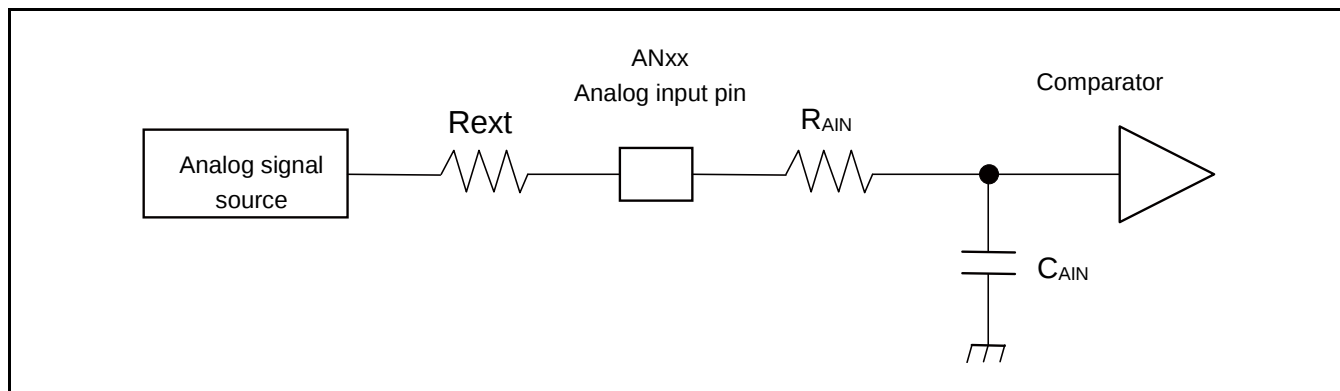
(ETHV_{CC} = 3.0V to 3.6V, 4.5V to 5.5V*¹, V_{SS} = 0V, C_L = 25 pF)

Parameter	Symbol	Pin Name	Conditions	Value		Unit
				Min	Max	
Transmission clock Cycle time* ²	t _{TXCYC}	E_TCK	100 Mbps 40 ns (typical)	-	-	ns
			100 Mbps 400 ns (typical)	-	-	ns
Transmission clock High-pulse-width duty cycle	t _{TXCYCH}	E_TCK	t _{TXCYCH} /t _{TXCYC}	35	65	%
Transmission clock Low-pulse-width duty cycle	t _{TXCYCL}	E_TCK	t _{TXCYCL} /t _{TXCYC}	35	65	%
TXCK ↑ → Transmitted data delay time	t _{MIITX}	E_TX03, E_TX02, E_TX01, E_TX00, E_TXEN	-	-	24	ns

*1: When ETHV = 4.5V to 5.5V, it is recommended to add a series resistor at the output pin to suppress the output current.

*2: The transmission clock is fixed to 25 MHz or 2.5 MHz in the MII specifications. The clock accuracy should meet the PHY-device specifications.





(Equation 1) $t_s \geq (R_{AIN} + R_{ext}) \times C_{AIN} \times 9$

t_s : Sampling time

R_{AIN} : Input resistance of A/D = 1.2 k Ω at 4.5 V $\leq AV_{CC} \leq 5.5$ V

Input resistance of A/D = 1.8 k Ω at 2.7 V $\leq AV_{CC} < 4.5$ V

C_{AIN} : Input capacity of A/D = 12.05 pF at 2.7 V $\leq AV_{CC} \leq 5.5$ V

R_{ext} : Output impedance of external circuit

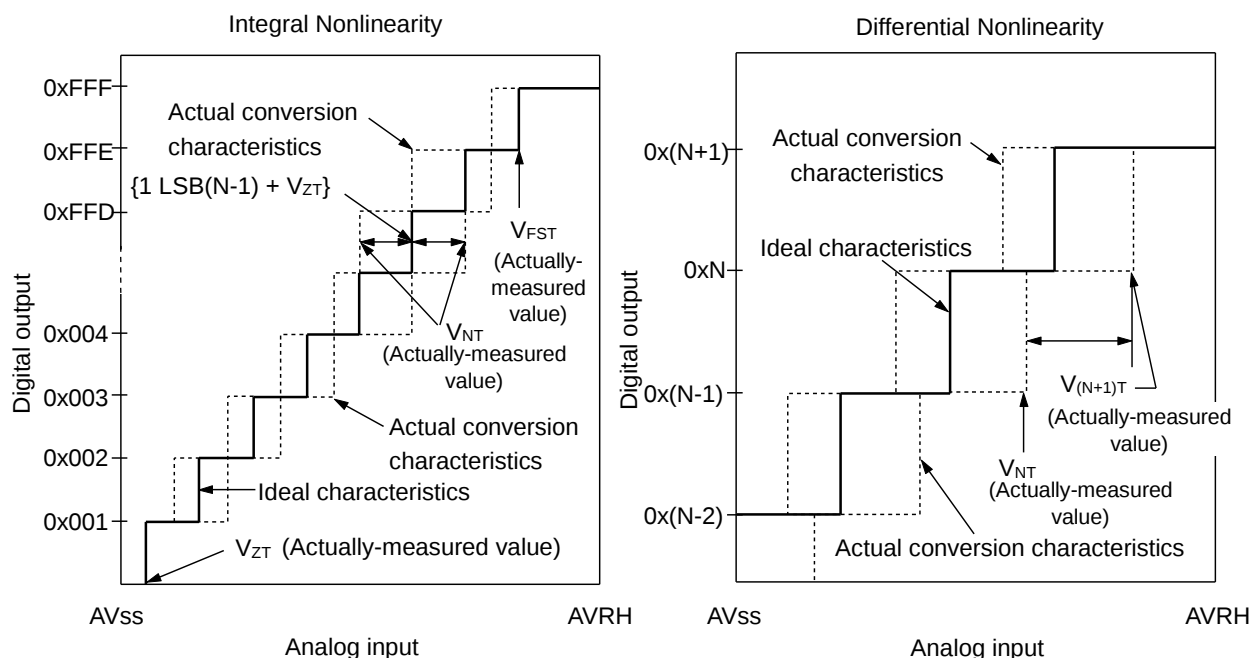
(Equation 2) $t_c = t_{CCK} \times 14$

t_c : Compare time

t_{CCK} : Compare clock cycle

Definition of 12-bit A/D Converter Terms

- **Resolution:** Analog variation that is recognized by an A/D converter.
- **Integral Nonlinearity:** Deviation of the line between the zero-transition point (0b000000000000 ↔ 0b000000000001) and the full-scale transition point (0b111111111110 ↔ 0b111111111111) from the actual conversion characteristics.
- **Differential Nonlinearity:** Deviation from the ideal value of the input voltage that is required to change the output code by 1 LSB.



$$\text{Integral Nonlinearity of digital output } N = \frac{V_{NT} - \{1\text{LSB} \times (N - 1) + V_{ZT}\}}{1\text{LSB}} \quad [\text{LSB}]$$

$$\text{Differential Nonlinearity of digital output } N = \frac{V_{(N+1)T} - V_{NT}}{1\text{LSB}} - 1 \quad [\text{LSB}]$$

$$1\text{LSB} = \frac{V_{FST} - V_{ZT}}{4094}$$

N: A/D converter digital output value.

V_{ZT}: Voltage at which the digital output changes from 0x000 to 0x001.

V_{FST}: Voltage at which the digital output changes from 0xFFE to 0xFFF.

V_{NT}: Voltage at which the digital output changes from 0x(N - 1) to 0xN.

12.11 Standby Recovery Time

12.11.1 Recovery Cause: Interrupt/WKUP

The time from the interrupt occurring to the time of program operation start is shown.

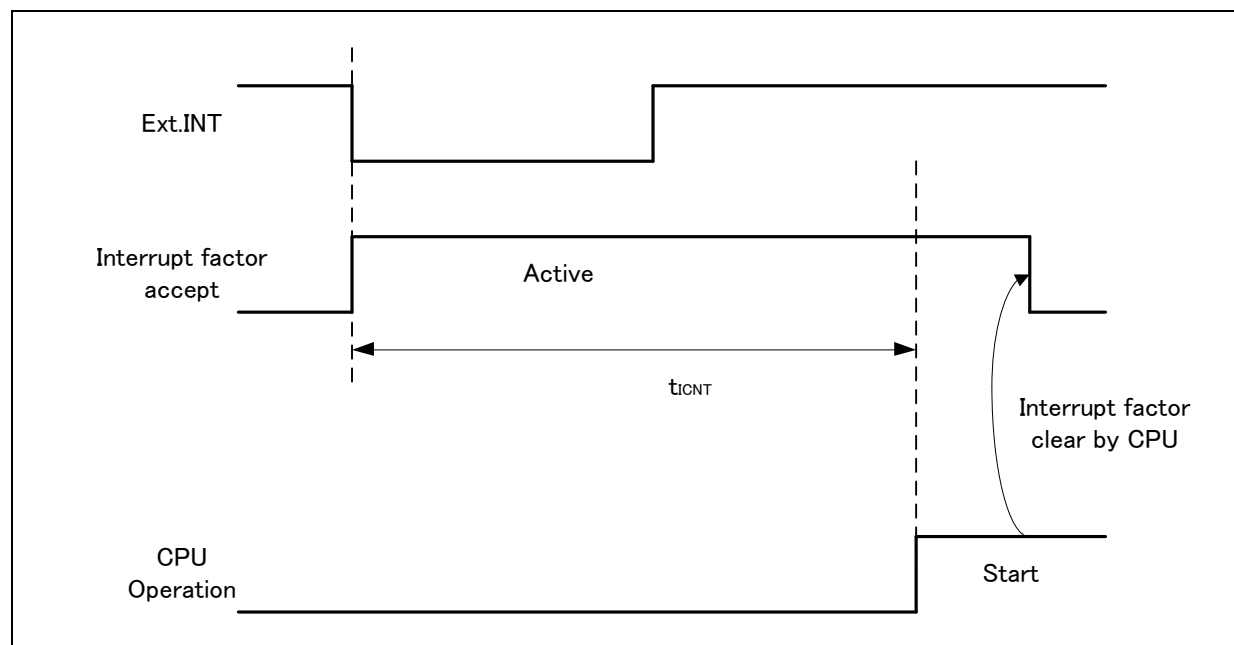
Recovery Count Time

($V_{CC} = 2.7V$ to $5.5V$, $V_{SS} = 0V$)

Parameter	Symbol	Value		Unit	Remarks
		Typ	Max*		
Sleep mode	t _{ICNT}	HCLK×1		μs	
High-speed CR Timer mode Main Timer mode PLL Timer mode		40	80	μs	
Low-speed CR Timer mode		450	900	μs	
Sub Timer mode		896	1136	μs	
RTC mode Stop mode (High-speed CR/Main/PLL Run mode return)		316	581	μs	
RTC mode Stop mode (Low-speed CR/sub Run mode return)		270	540	μs	
Deep Standby RTC mode with RAM retention		365	667	μs	without RAM retention
Deep Standby Stop mode with RAM retention		365	667	μs	with RAM retention

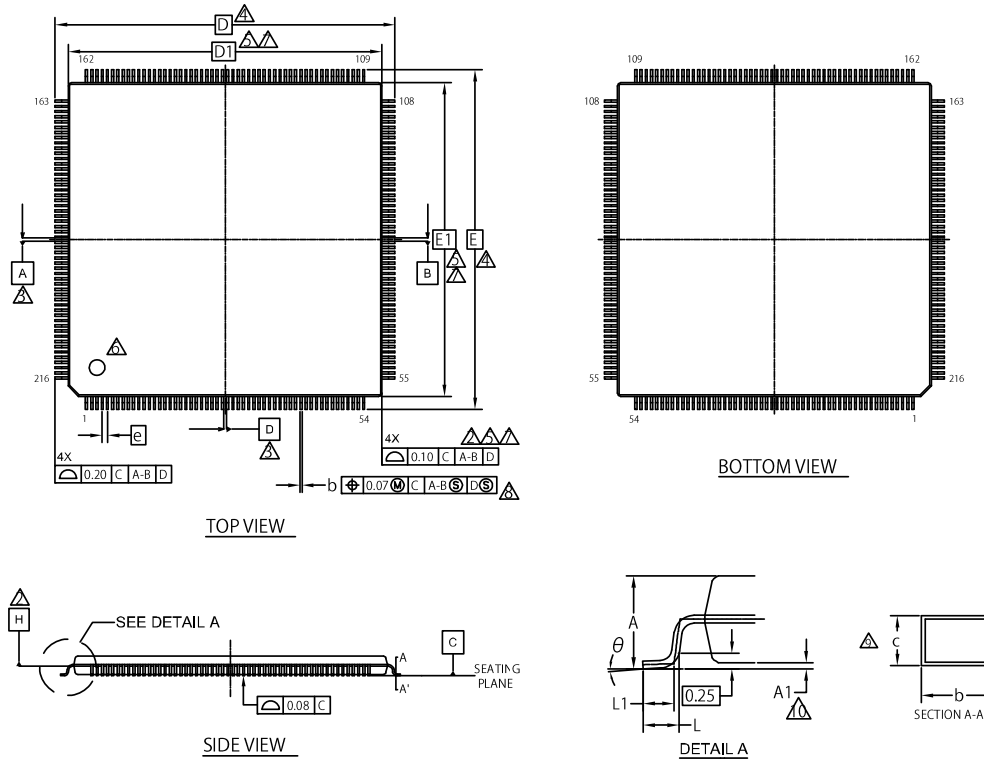
*: The maximum value depends on the built-in CR accuracy.

Example of Standby Recovery Operation (when in External Interrupt Recovery*)



*: External interrupt is set to detecting fall edge.

Package Type	Package Code
LQFP 216	LQQ 216



SYMBOL	DIMENSIONS		
	MIN.	NOM.	MAX.
A	—	—	1.70
A1	0.05	—	0.15
b	0.13	0.18	0.23
c	0.09	—	0.20
D	26.00 BSC.		
D1	24.00 BSC.		
e	0.40 BSC.		
E	26.00 BSC.		
E1	24.00 BSC.		
L	0.45	0.60	0.75
L1	0.30	0.50	0.70
θ	0°	—	8°

NOTES

- ALL DIMENSIONS ARE IN MILLIMETERS.
- DATUM PLANE H IS LOCATED AT THE BOTTOM OF THE MOLD PARTING LINE COINCIDENT WITH WHERE THE LEAD EXITS THE BODY.
- DATUMS A-B AND D TO BE DETERMINED AT DATUM PLANE H.
- TO BE DETERMINED AT SEATING PLANE C.
- DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PRE SIDE. DIMENSIONS D1 AND E1 INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
- DETAILS OF PIN 1 IDENTIFIER ARE OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED.
- REGARDLESS OF THE RELATIVE SIZE OF THE UPPER AND LOWER BODY SECTIONS, DIMENSIONS D1 AND E1 ARE DETERMINED AT THE LARGEST FEATURE OF THE BODY EXCLUSIVE OF MOLD FLASH AND GATE BURRS. BUT INCLUDING ANY MISMATCH BETWEEN THE UPPER AND LOWER SECTIONS OF THE MOLDER BODY.
- DIMENSION b DOES NOT INCLUDE DAMBER PROTRUSION. THE DAMBER PROTRUSION (S) SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED b MAXIMUM BY MORE THAN 0.08mm. DAMBER CANNOT BE LOCATED ON THE LOWER RADIUS OR THE LEAD FOOT.
- THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm AND 0.25mm FROM THE LEAD TIP.
- A1 IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.

002-15153 **

PACKAGE OUTLINE, 216 LEAD LQFP
24.0X24.0X1.7 MM LQFP216 REV**